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FDB8441 N-Channel PowerTrench[®] MOSFET

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FDB8441

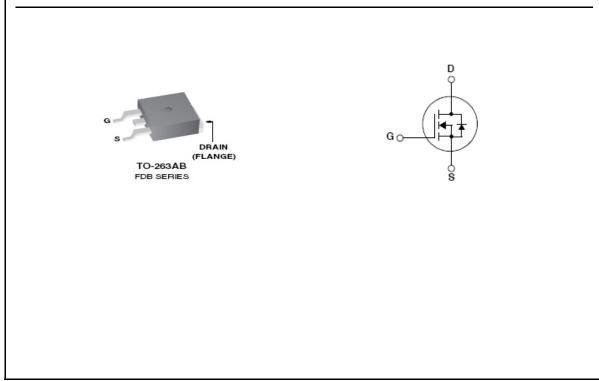
N-Channel PowerTrench[®] MOSFET 40V, 120A, 2.5m Ω

Features

- Typ $r_{DS(on)}$ = 1.9m Ω at V_{GS} = 10V, I_D = 80A
- Typ Q_{g(10)} = 215nC at V_{GS} = 10V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- RoHS Compliant

Applications

- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alternator
- Distributed Power Architectures and VRMs
- Primary Switch for 12V Systems



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Symbol	Parameter	Ratings	Units
V _{DS}	Drain to Source Voltage	40	V
V _{GS}	Gate to Source Voltage	±20	V
	Drain Current Continuous (T _C = 25°C, Silicon limited)	262*	
	Drain Current Continuous (T _C = 100°C, Silicon limited)	185*	
I _D	Drain Current Continuous (T _C = 25°C, Package limited)	120	Α
	Drain Current Continuous (T _A = 25°C, $R_{\theta JA}$ = 43°C/W)	28	
	Pulsed	See Figure 4	
E _{AS}	Single Pulse Avalanche Energy (Note	1) 947	mJ
n	Power dissipation	300	W
P _D	Derate above 25°C	2	W/ºC
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C

*Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 120A.

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.5	°C/W
$R_{ hetaJA}$	Thermal Resistance Junction to Ambient (Note 2)	62	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient, 1in ² copper pad area	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8441	FDB8441	TO-263AB	330mm	24mm	800 units

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

	Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
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Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _G	_{iS} = 0V	40	-	-	V
1	Zero Gate Voltage Drain Current	V _{DS} = 32V		-	-	1	
DSS	Zero Gate Voltage Drain Current	$V_{GS} = 0V$	T _J = 150°C	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	2.8	4	V
		I _D = 80A, V _{GS} = 10V	-	1.9	2.5	
r _{DS(on)}	Drain to Source On Resistance	I _D = 80A, V _{GS} = 10V, T _J = 175°C	-	3.3	4.3	mΩ

Dynamic Characteristics

Ciss	Input Capacitance		- 0)/	-	15000	-	pF
C _{oss}	Output Capacitance		V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		1250	-	pF
C _{rss}	Reverse Transfer Capacitance				685	-	pF
R _G	Gate Resistance	V _{GS} = 0.5V, f = 1	MHz	-	1.1	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V		-	215	280	nC
Q _{g(TH)}	Threshold Gate Charge	V_{GS} = 0 to 2V	V _{DD} = 20V	-	29	38	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 35A	-	60	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		I _g = 1mA	-	32	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		-	-	49	-	nC

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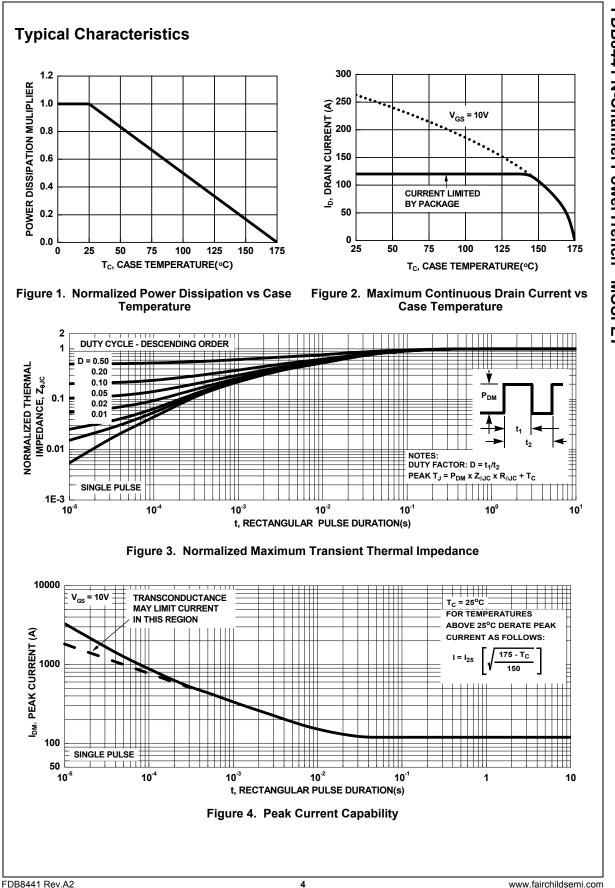
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switching	g Characteristics					
t _(on)	Turn-On Time		-	-	77	ns
t _{d(on)}	Turn-On Delay Time		-	23	-	ns
t r	Turn-On Rise Time	V _{DD} = 20V, I _D = 35A	-	24	-	ns
td(off)	Turn-Off Delay Time	V_{DD} = 20V, I _D = 35A V _{GS} = 10V, R _{GS} = 1.5Ω	-	75	-	ns
f	Turn-Off Fall Time		-	17.9	-	ns
t _{off}	Turn-Off Time		-	-	147	ns

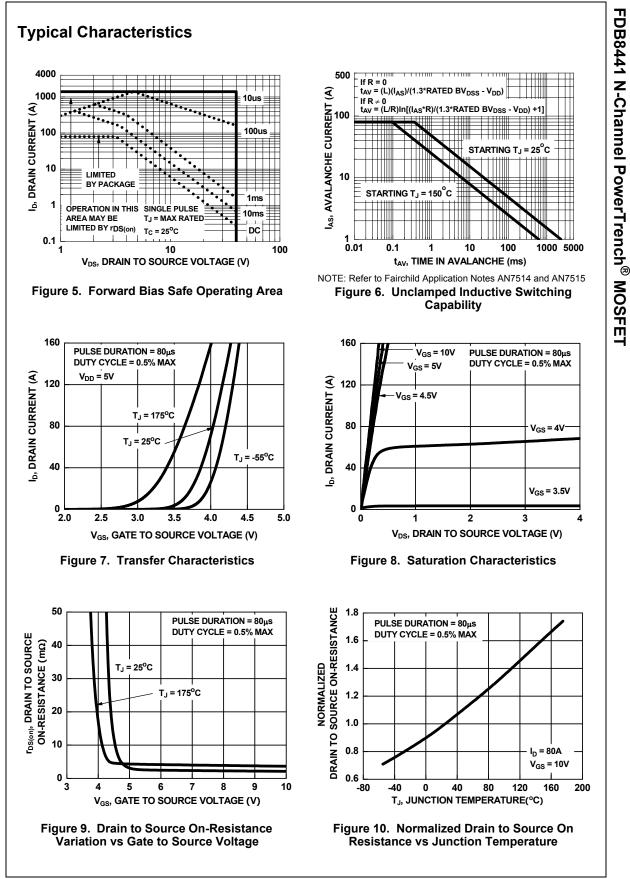
V _{SD} Source to Drain Diode Voltage		I _{SD} = 35A	-	0.8	1.25	V
V _{SD}	Source to Drain Diode voltage	I _{SD} = 15A	-	0.8	1.0	V
t _{rr}	Reverse Recovery Time	I _F = 35A, di/dt = 100A/μs	-	52	68	ns
Q _{rr}	Reverse Recovery Charge	I _F = 35A, di/dt = 100A/μs	-	76	99	nC

Notes: 1: Starting $T_J = 25^{\circ}C$, L = 0.46mH, I_{AS} = 64A. **2:** Pulse width = 100s.

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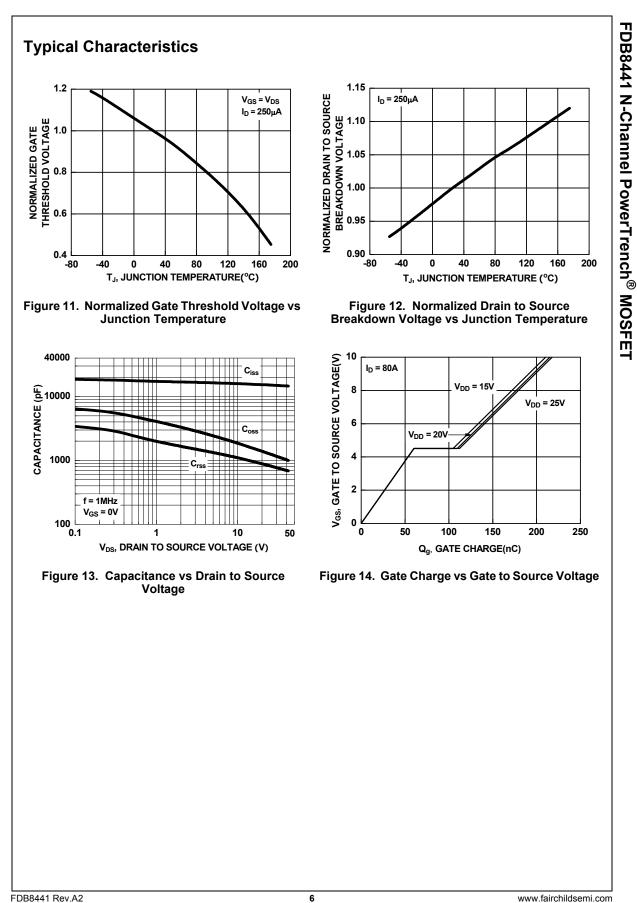
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